

# 2SD476(K), 2SD476A(K)

Silicon NPN Triple Diffused

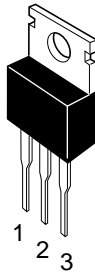
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## Application

Power switching complementary pair with 2SB566(K) and 2SB566A(K)

## Outline

TO-220AB



1. Base
2. Collector (Flange)
3. Emitter

## Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings		Unit
		2SD476(K)	2SD476A(K)	
Collector to base voltage	$V_{CBO}$	70	70	V
Collector to emitter voltage	$V_{CEO}$	50	60	V
Emitter to base voltage	$V_{EBO}$	5	5	V
Collector current	$I_C$	4	4	A
Collector peak current	$I_{C(peak)}$	8	8	A
Collector power dissipation	$P_C^{*1}$	40	40	W
Junction temperature	$T_j$	150	150	°C
Storage temperature	$T_{stg}$	-55 to +150	-55 to +150	°C

Note: 1. Value at  $T_c = 25^\circ\text{C}$

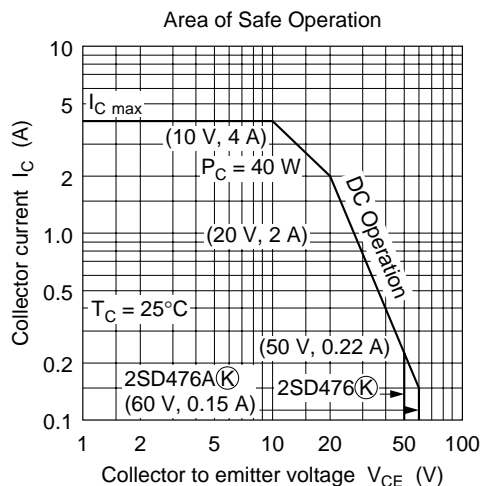
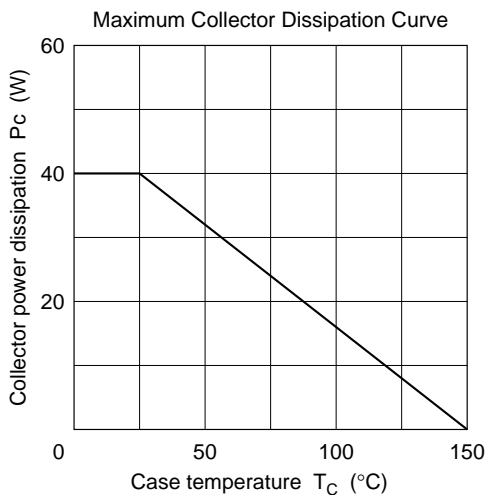
# 2SD476(K), 2SD476A(K)

## Electrical Characteristics (Ta = 25°C)

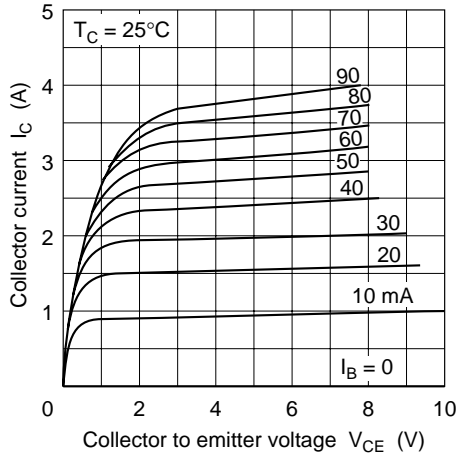
Item	Symbol	2SD476(K)			2SD476A(K)			Unit	Test conditions
		Min	Typ	Max	Min	Typ	Max		
Collector to base breakdown voltage	$V_{(BR)CBO}$	70	—	—	70	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	50	—	—	60	—	—	V	$I_C = 50 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	5	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	1	—	—	1	$\mu A$	$V_{CB} = 50 \text{ V}, I_E = 0$
DC current transfer ratio	$h_{FE1}$	60	—	200	60	—	200		$V_{CE} = 4 \text{ V}, I_C = 1 \text{ A}$ (Pulse test)
	$h_{FE2}$	35	—	—	35	—	—		$V_{CE} = 4 \text{ V}, I_C = 0.1 \text{ A}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	—	—	1.0	V	$I_C = 2 \text{ A}, I_B = 0.2 \text{ A}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.2	—	—	1.2	V	
Gain bandwidth product	$f_T$	—	7	—	—	7	—	MHz	$V_{CE} = 4 \text{ V}, I_C = 0.5 \text{ A}$
Turn on time	$t_{on}$	—	0.3	—	—	0.3	—	$\mu s$	$V_{CC} = 10.5 \text{ V}$
Turn off time	$t_{off}$	—	3.0	—	—	3.0	—	$\mu s$	$I_C = 10 \text{ I}_{B1} = -10 \text{ I}_{B2} =$
Storage time	$t_{stg}$	—	2.5	—	—	2.5	—	$\mu s$	0.5 A

Note: 1. The 2SD476(K) and 2SD476A(K) are grouped by  $h_{FE1}$  as follows.

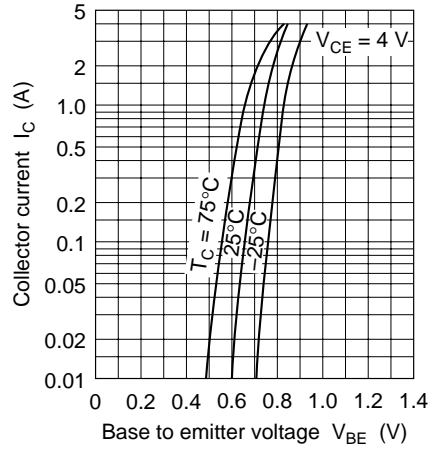
B	C
60 to 120	100 to 200



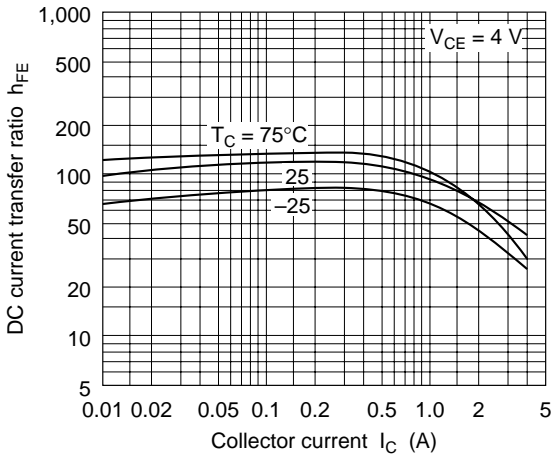
Typical Output Characteristics



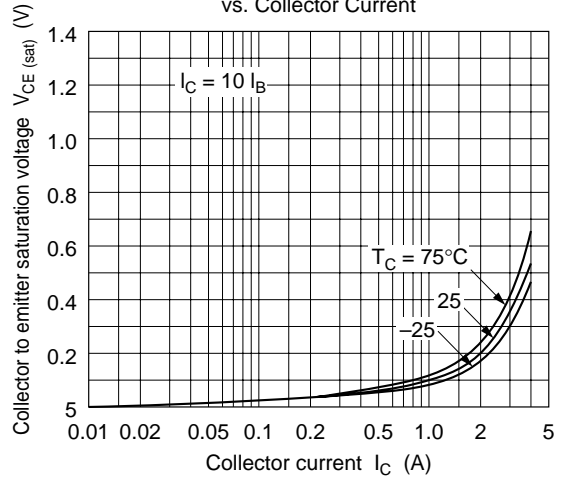
Typical Transfer Characteristics

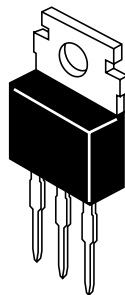
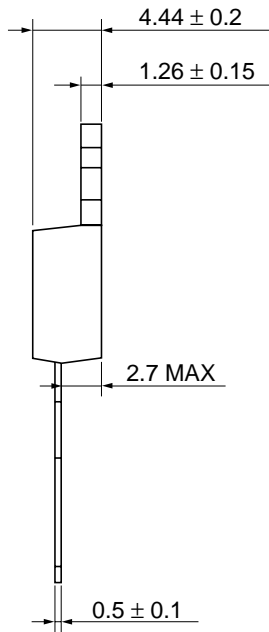
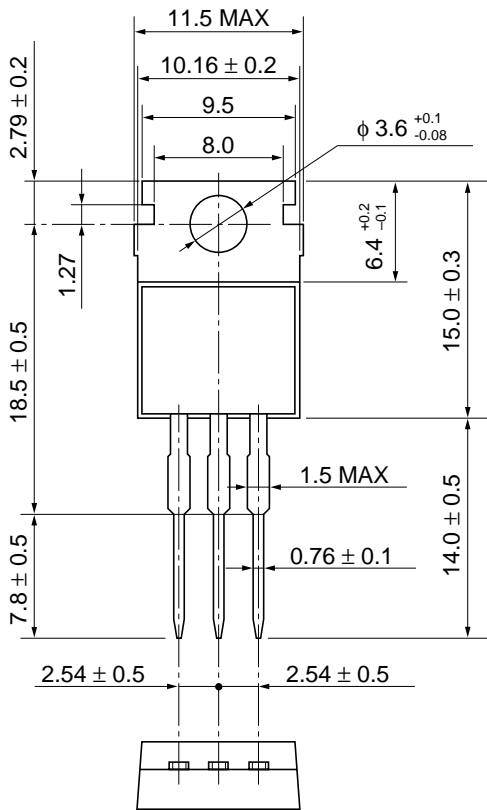


DC Current Transfer Ratio vs. Collector Current



Collector to Emitter Saturation Voltage vs. Collector Current





Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.8 g

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